



ACE17440M

N-Channel 40-V (D-S) MOSFET

Features

- Low $r_{DS(on)}$ trench technology
- Low thermal impedance
- Fast switching speed

PRODUCT SUMMARY

V_{DS} (V)	$r_{DS(on)}$ (m Ω)	I_D (A)
40	15 @ $V_{GS} = 10V$	15
	18 @ $V_{GS} = 4.5V$	14

Applications

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

Absolute Maximum Ratings

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	40	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ^a	I_D	$T_A = 25^\circ C$ 15	A
		$T_A = 70^\circ C$ 12	
Pulse Drain Current ^b	I_{DM}	50	
Continuous Drain Current (Diode Continuous) ^a	I_S	6.4	A
Power Dissipation ^a	P_D	$T_A = 25^\circ C$ 5	W
		$T_A = 70^\circ C$ 3.2	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	$^\circ C$

Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	$t \leq 10\text{sec}$ 25	$^\circ C/W$
		Steady State 65	$^\circ C/W$

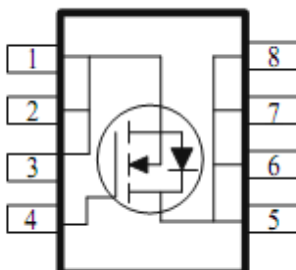
Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

Packaging Type

DFN5*6-8L



Ordering information

ACE17440M XX + H

- Halogen - free
- Pb - free
- PN: DFN5*6-8L



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Electrical Characteristics

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static						
Gate Source Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1			V
Gate Body Leakage	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=32V, V_{GS}=0V$			1	uA
		$V_{DS}=32V, V_{GS}=0V, T_J=55^\circ C$			25	
On-State Drain-Current ^a	$I_{D(on)}$	$V_{DS}=5V, V_{GS}=10V$	25			A
Static Drain-Source On-Resistance ^a	$r_{DS(on)}$	$V_{GS}=10V, I_D=12A$			15	mΩ
		$V_{GS}=4.5V, I_D=9.6A$			18	
Forward Transconductance ^a	g_{fs}	$V_{DS}=15V, I_D=12A$		22		S
Diode Forward Voltage ^a	V_{SD}	$I_S=3.2A, V_{GS}=0V$		0.75		V
Dynamic ^b						
Total Gate Charge	Q_g	$V_{DS}=20V, V_{GS}=4.5V,$ $I_D=12A$		19		nC
Gate-Source Charge	Q_{gs}			5.0		
Gate-Drain Charge	Q_{gd}			9.1		
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=20V, R_L=1.7\Omega$ $I_D=12A, V_{GEN}=10V$ $R_{GEN}=6\Omega,$		7		ns
Rise Time	t_f			38		
Turn-Off Delay Time	$t_{d(off)}$			62		
Fall Time	t_f			24		
Input Capacitance	C_{iss}	$V_{DS}=15V, V_{GS}=0V$ $f=1MHz$		1826		pF
Output Capacitance	C_{oss}			253		
Reverse Transfer Capacitance	C_{rss}			208		

Note:

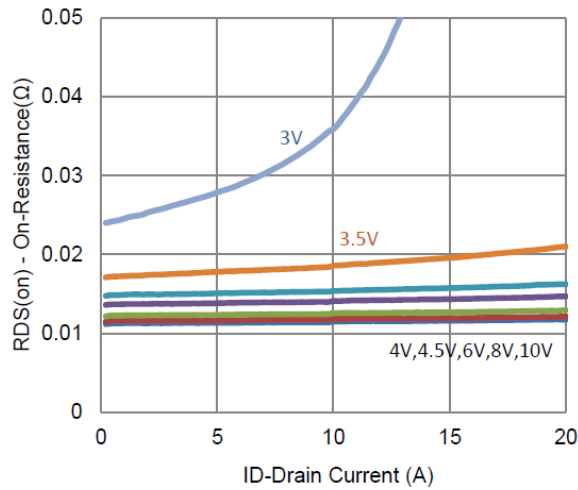
- a. Pulse test: PW ≤ 300us duty cycle ≤ 2%.
- b. Guaranteed by design, not subject to production testing.



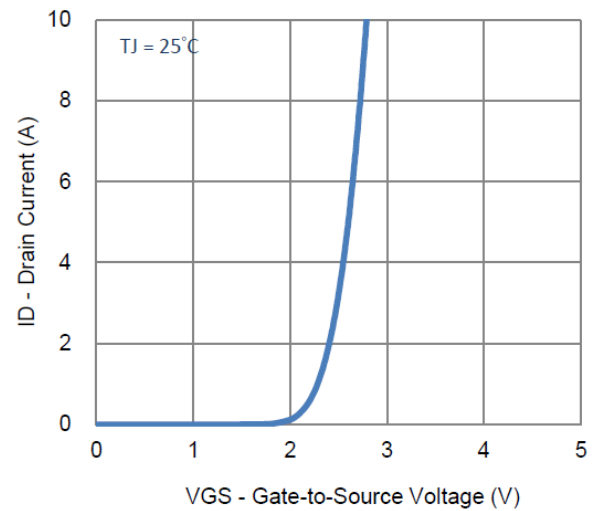
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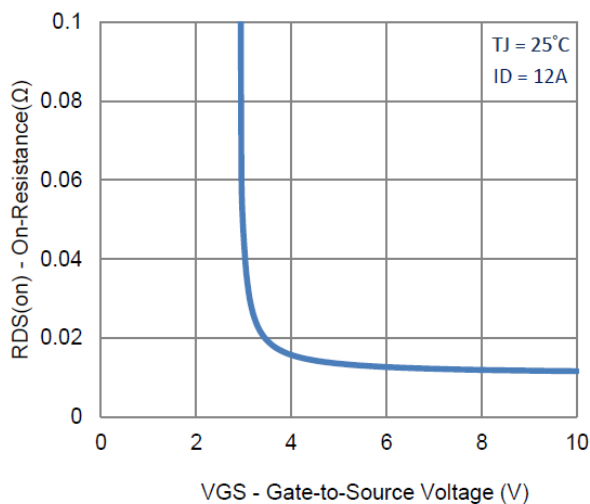
Typical Electrical Characteristics



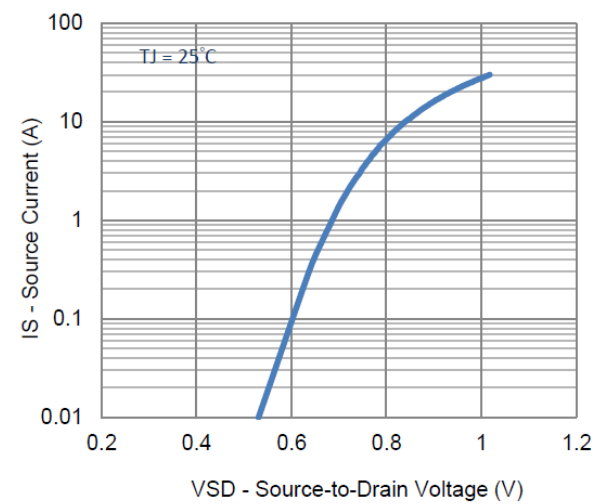
1. On-Resistance vs. Drain Current



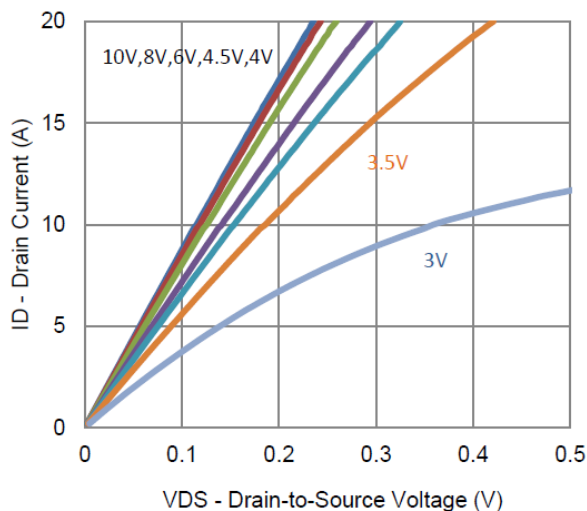
2. Transfer Characteristics



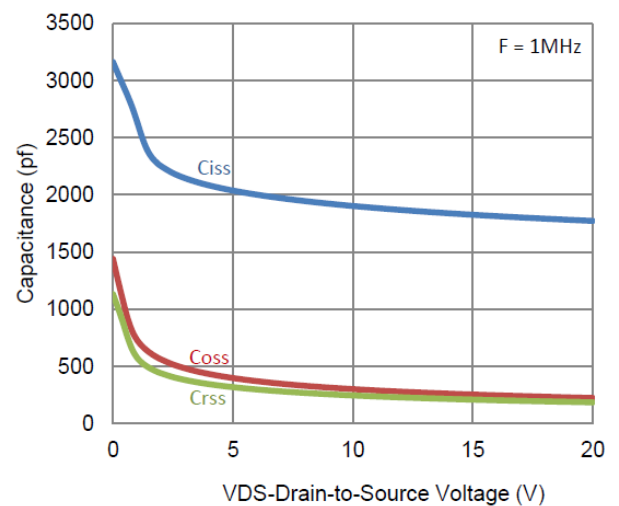
3. On-Resistance vs. Gate-to-Source Voltage



4. Drain-to-Source Forward Voltage



5. Output Characteristics

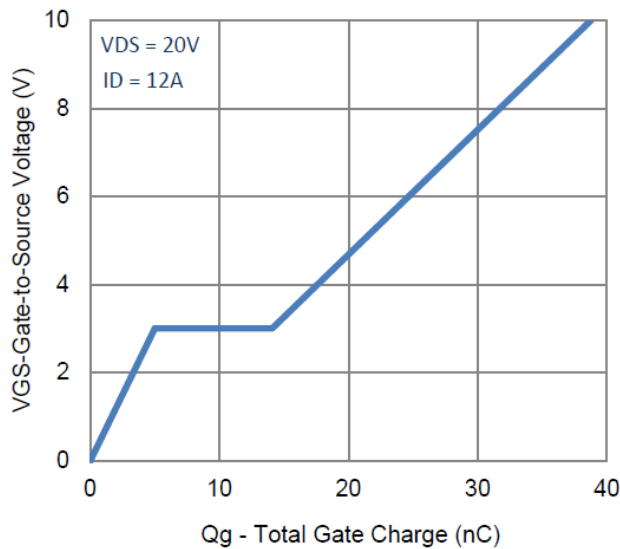


6. Capacitance

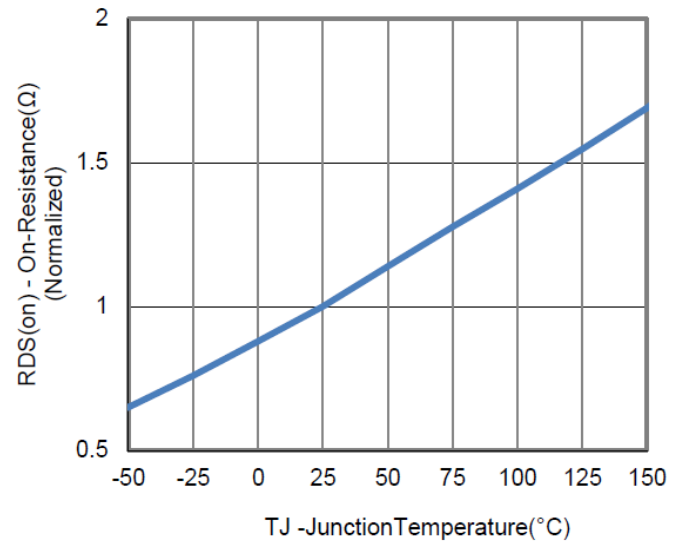


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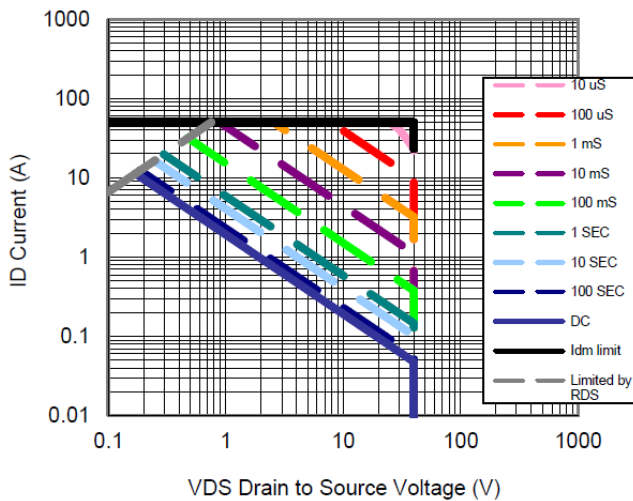
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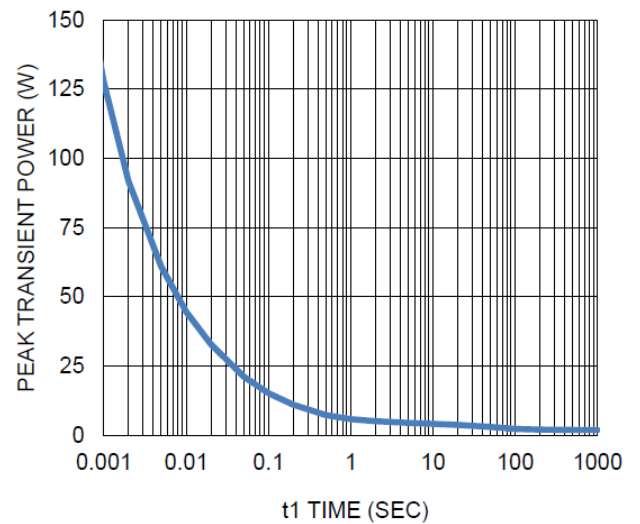
7. Gate Charge



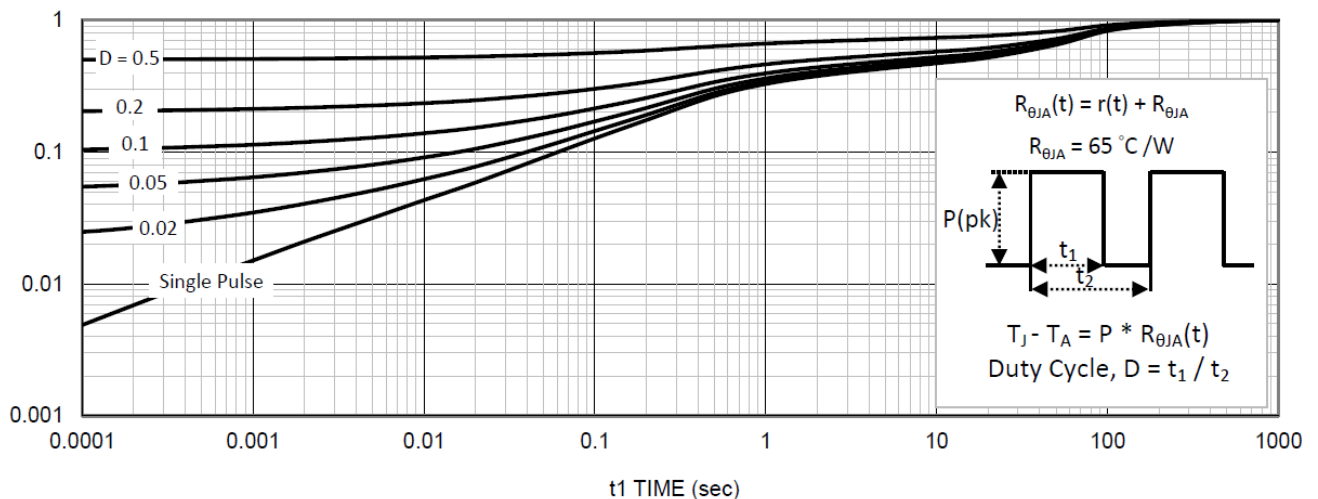
8. Normalized On-Resistance Vs Junction Temperature



9. Safe Operating Area



10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

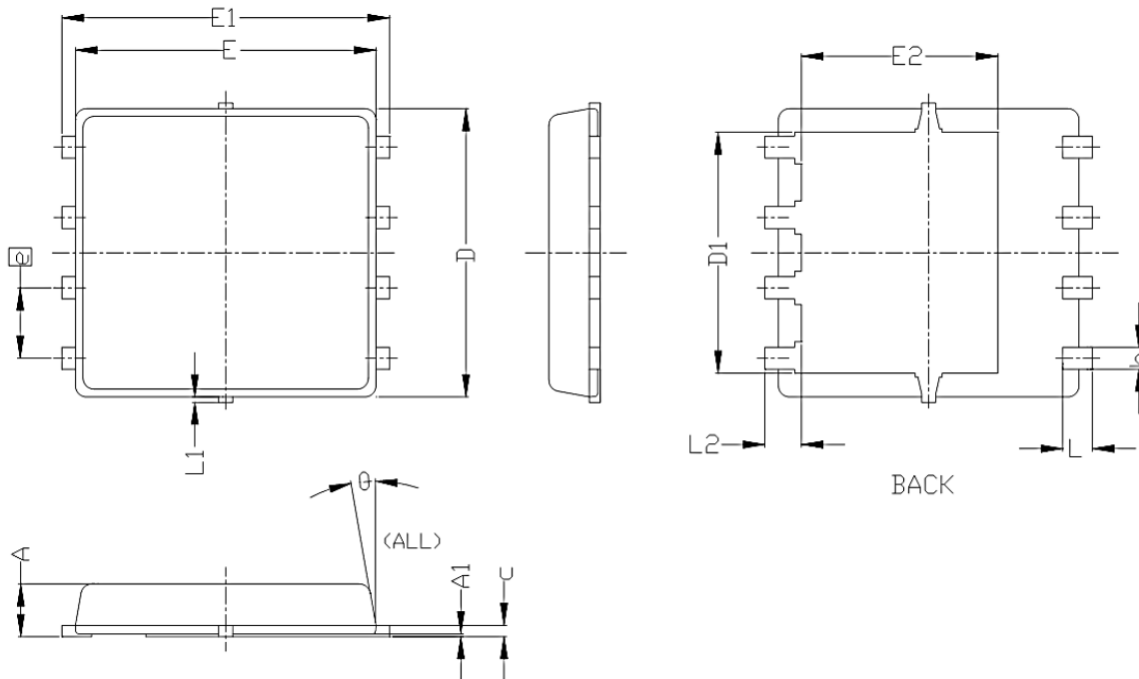


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Packing Information

DFN5*6-8L



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.85			0.033	0.037	0.039
A1	0.00			0.000		0.002
b	0.30			0.012	0.016	0.020
c	0.15			0.006	0.008	0.010
D	5.20BSC			0.205BSC		
D1	4.35BSC			0.171BSC		
E	5.55BSC			0.219BSC		
E1	6.05BSC			0.238BSC		
E2	3.62BSC			0.143BSC		
e	1.27BSC			0.050BSC		
L	0.45	0.55	0.65	0.018	0.022	0.026
L1	0		0.15	0		0.006
L2	0.68REF			0.027REF		
θ1	0°		10°	0°		10°



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Notes

ACE does not assume any responsibility for use as critical components in life support devices or systems without the express written approval of the president and general counsel of ACE Electronics Co., LTD. As sued herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.